



RN1611(TE85L,F) Information



For Reference Only

Part Number RN1611(TE85L,F)

ManufacturerToshiba Semiconductor and StorageCategoryDiscrete Semiconductor Products

Transistors - Bipolar (BJT) - Arrays, Pre-Biased

Description TRANS 2NPN PREBIAS 0.3W SM6

Package SC-74, SOT-457

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RN1611(TE85L,F) Specifications

	Report errors?
Supplier Device Package	SM6
Package / Case	SC-74, SOT-457
Mounting Type	Surface Mount
Power - Max	300mW
Frequency - Transition	250MHz
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	300mV @ 250μA, 5mA
DC Current Gain (hFE) (Min) @ Ic, Vce	120 @ 1mA, 5V
Resistor - Emitter Base (R2) (Ohms)	-
Resistor - Base (R1) (Ohms)	10k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	2 NPN - Pre-Biased (Dual)
Series	-
Package	SC-74, SOT-457
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Toshiba Semiconductor and Storage
Manufacturer Part Number	RN1611(TE85L,F)

RN1611(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1611(TE85L,F) Payment Methods



















RN1611(TE85L,F) Shipping Methods













If you have any question about RN1611(TE85L,F), please do not hesitate to contact us!

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